

# RJK1003DPN-E0

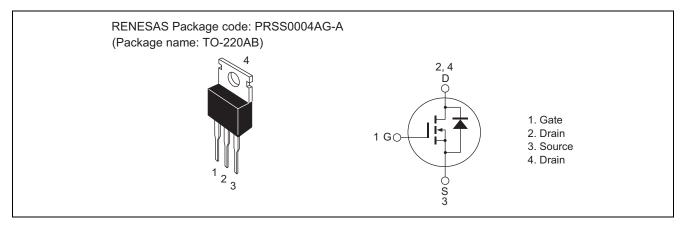
N-Channel MOS FET 100 V, 50 A, 11 m $\Omega$ 

R07DS0621EJ0200 Rev.2.00 Aug 24, 2012

## Features

- High speed switching
- Low drive current
- Low on-resistance  $R_{DS(on)} = 8.8 \text{ m}\Omega \text{ typ.}$  (at  $V_{GS} = 10 \text{ V}$ )
- Package TO-220AB

#### Outline



## **Absolute Maximum Ratings**

	$(Ta = 25^{\circ}C)$	
Symbol	Ratings	Unit
V <sub>DSS</sub>	100	V
V <sub>GSS</sub>	±20	V
I <sub>D</sub>	50	А
I <sub>D (pulse)</sub> Note1	150	А
I <sub>DR</sub>	50	А
I <sub>AP</sub> Note2	25	А
E <sub>AS</sub> Note2	63	mJ
Pch Note3	125	W
θch-c	1.0	°C/W
Tch	150	٥C
Tstg	-55 to +150	°C
	V <sub>DSS</sub> V <sub>GSS</sub> I <sub>D</sub> I <sub>D (pulse)</sub> <sup>Note1</sup> I <sub>DR</sub> I <sub>AP</sub> <sup>Note2</sup> E <sub>AS</sub> <sup>Note2</sup> E <sub>AS</sub> <sup>Note2</sup> Pch <sup>Note3</sup> θch-c Tch	$\begin{tabular}{ c c c c c c c } \hline V_{DSS} & 100 \\ \hline V_{GSS} & \pm 20 \\ \hline I_D & 50 \\ \hline I_{D (pulse)}^{Note1} & 150 \\ \hline I_{DR} & 50 \\ \hline I_{AP}^{Note2} & 25 \\ \hline E_{AS}^{Note2} & 63 \\ \hline Pch^{Note3} & 125 \\ \hline \thetach-c & 1.0 \\ \hline Tch & 150 \\ \hline \end{tabular}$

Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

2. Value at L = 100  $\mu H$  , Tch = 25°C, Rg  $\geq 50 \Omega,$ 

3. Tc = 25°C



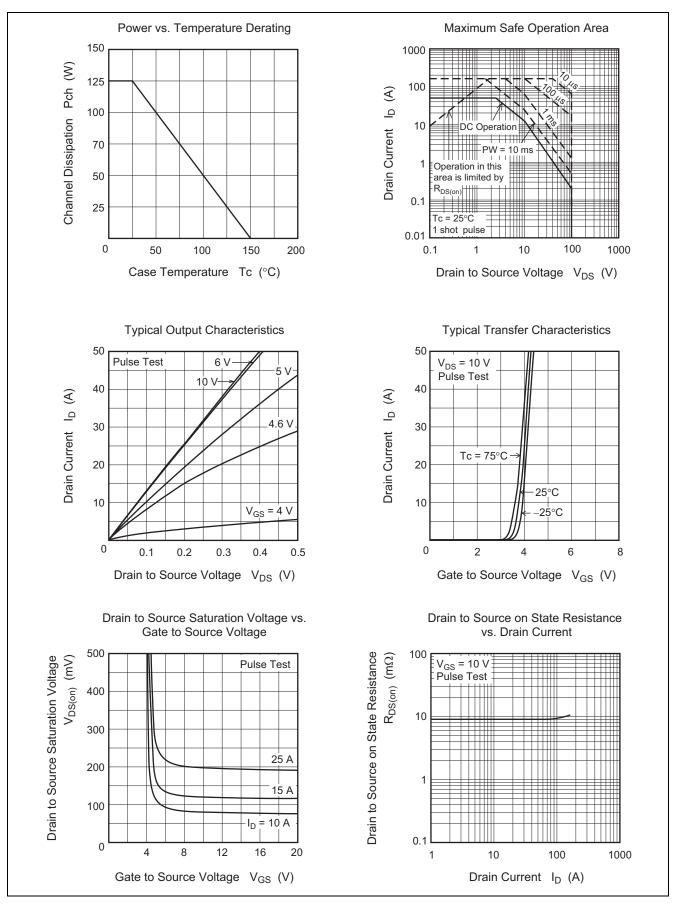
## **Electrical Characteristics**

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	100	—	—	V	$I_D = 10mA, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	—	±0.1	μΑ	$V_{GS} = \pm 20$ V, $V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 100 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	2.0	—	4.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state resistance	R <sub>DS(on)</sub>	_	8.8	11.0	mΩ	$I_D = 25 \text{ A}, \text{ V}_{GS} = 10 \text{ V}^{Note4}$
Forward transfer admittance	y <sub>fs</sub>	_	100	_	S	$I_D = 25 \text{ A}, V_D = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	4150	_	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	_	660	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	160	_	pF	
Gate Resistance	Rg	_	1.6	—	Ω	
Total gate charge	Qg	_	59	—	nC	V <sub>DD</sub> = 50 V
Gate to source charge	Qgs	_	20	—	nC	$V_{GS} = 10 V,$ $I_D = 25 A$
Gate to drain charge	Qgd	—	12	—	nC	
Turn-on delay time	t <sub>d(on)</sub>	—	30	—	ns	$\label{eq:VGS} \begin{array}{l} V_{GS} = 10 \ V \\ I_D = 25 \ A \\ V_{DD} \cong 30 \ V \\ Rg = 4.7 \ \Omega \end{array}$
Rise time	tr	—	9	—	ns	
Turn-off delay time	t <sub>d(off)</sub>	—	60	—	ns	
Fall time	t <sub>f</sub>	_	10	_	ns	
Body-drain diode forward voltage	V <sub>DF</sub>	_	0.85	1.5	V	$I_F = 50 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	55	—	ns	$I_F = 50 \text{ A},  V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

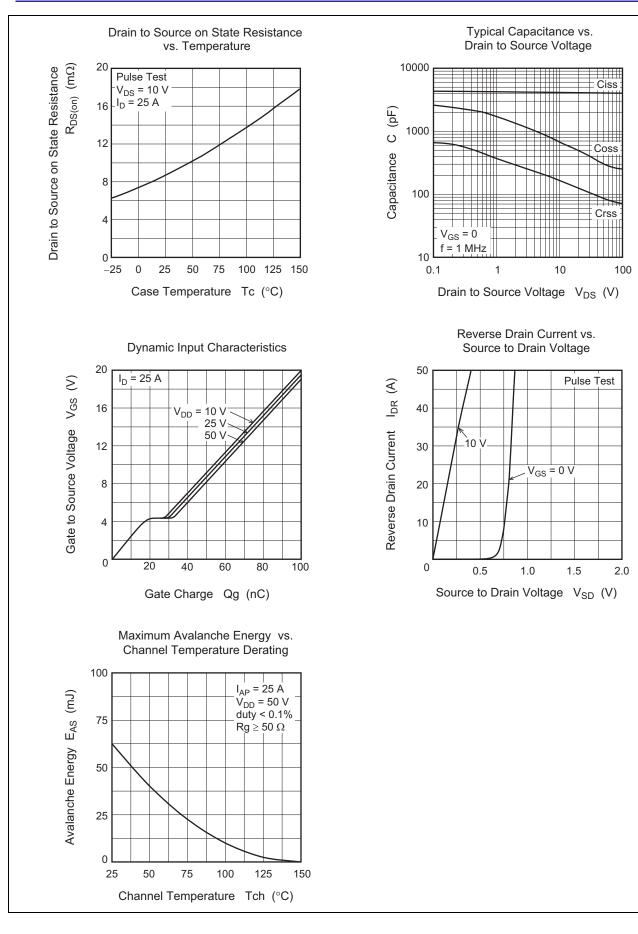
Notes: 4. Pulse test

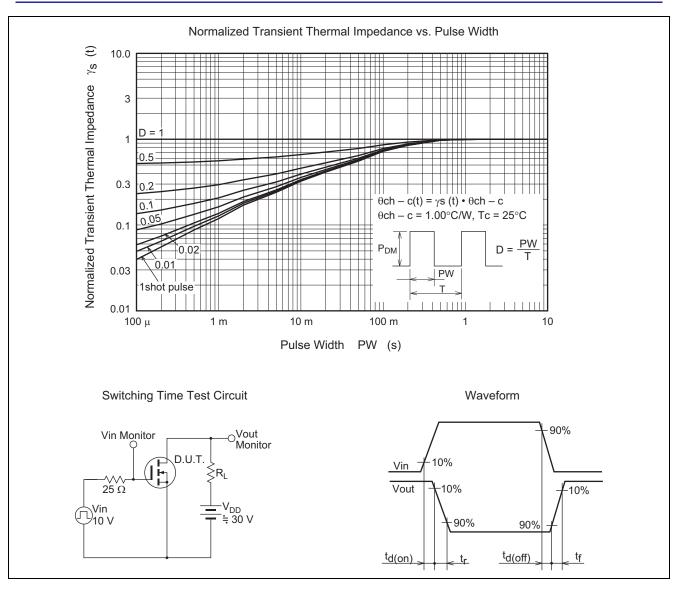


#### **Main Characteristics**



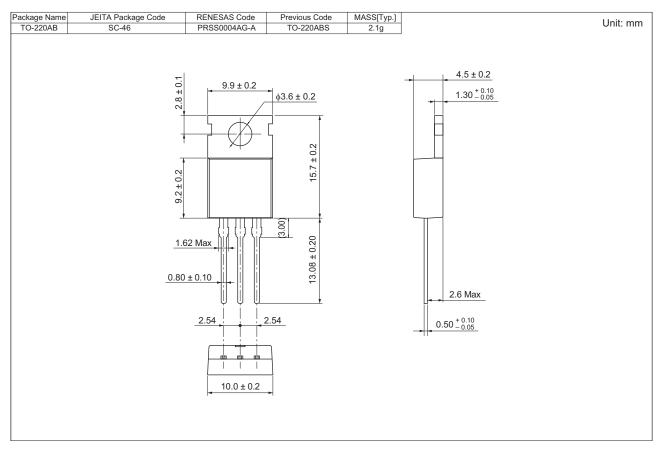








## **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJK1003DPN-E0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".



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